



**Product data sheet** 

## **1** Product profile

#### 1.1 General description

Planar PIN diode in a SOD323 small SMD plastic package.

#### **1.2 Features and benefits**

- High voltage, current controlled
- RF resistor for RF switches
- · Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- AEC-Q101 qualified

### **1.3 Applications**

- RF attenuators and switches
- Bandswitch for TV tuners
- Series diode for mobile communication transmit/receive switch.



### 2 Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode		
2	anode		₩ sym006
		Top view	

### **3** Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
BAP65-03	-	plastic surface-mounted package; 2 leads	SOD323			

### 4 Marking

Table 3. Marking	
Type number	Marking code
BAP65-03	D3 <sup>[1]</sup>

[1] The marking bar indicates the cathode (see simplified outline graphic in <u>Table 1</u>)

### 5 Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>R</sub>	continuous reverse voltage		-	30	V
l <sub>F</sub>	continuous forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> ≤ 90 °C	-	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

### **6** Thermal characteristics

#### Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		120	K/W

## 7 Characteristics

#### Table 6. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA		-	0.9	1.1	V	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 20 V		-	-	20	nA	
C <sub>d</sub>	diode capacitance	f = 1 MHz (see <u>Figure 1</u> )						
		V <sub>R</sub> = 0 V		-	0.65	-	pF	
		V <sub>R</sub> = 1 V		-	0.55	0.9	pF	
		V <sub>R</sub> = 3 V		-	0.5	0.8	pF	
		V <sub>R</sub> = 20 V		-	0.375	-	pF	
r <sub>D</sub>	diode forward resistance	f = 100 MHz (see Figure 2)		1				
		I <sub>F</sub> = 1 mA		-	1	-	Ω	
		I <sub>F</sub> = 5 mA	[1]	-	0.65	0.95	Ω	
		I <sub>F</sub> = 10 mA	[1]	-	0.56	0.9	Ω	
		I <sub>F</sub> = 100 mA		-	0.35	-	Ω	
SL	isolation	$V_R = 0 V (see Figure 4)$						
		f = 900 MHz		-	10.2	-	dB	
		f = 1800 MHz		-	5.8	-	dB	
		f = 2450 MHz		-	4.1	-	dB	
L <sub>ins</sub>	insertion loss See Figure 3.							
		I <sub>F</sub> = 1 mA						
		f = 900 MHz		-	0.11	-	dB	
		f = 1800 MHz		-	0.14	-	dB	
		f = 2450 MHz		-	0.18	-	dB	
		I <sub>F</sub> = 5 mA						
		f = 900 MHz		-	0.06	-	dB	
		f = 1800 MHz		-	0.10	-	dB	
		f = 2450 MHz		-	0.14	-	dB	
		I <sub>F</sub> = 10 mA						
		f = 900 MHz		-	0.06	-	dB	
		f = 1800 MHz		-	0.1	-	dB	
		f = 2450 MHz		-	0.13	-	dB	
-ins	insertion loss	I <sub>F</sub> = 100 mA						
		f = 900 MHz		-	0.05	-	dB	
		f = 1800 MHz		-	0.1	-	dB	
		f = 2450 MHz		-	0.14	-	dB	
				1	1	1		

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BAP65-03

Silicon Pin diode

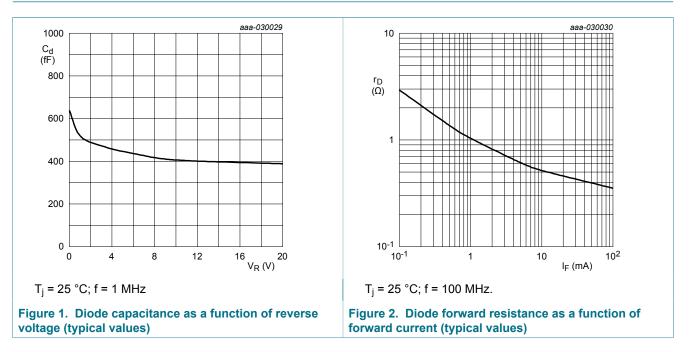
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
τι		when switched from $I_F = 10 \text{ mA}$ to $I_R = 6 \text{ mA}$ ; $R_L = 100 \Omega$ ; measured at $I_R = 3 \text{ mA}$	-	0.17	-	μs
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	1.5	-	nH

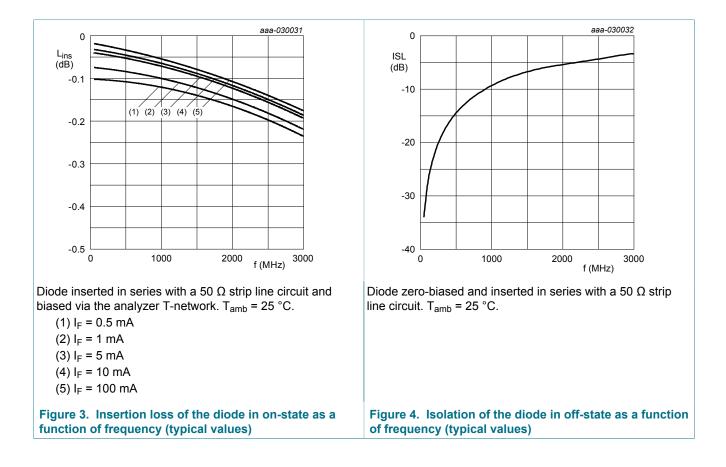
[1] Guaranteed on AQL basis; inspection level S4, AQL 1.0

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### 8 Graphical data

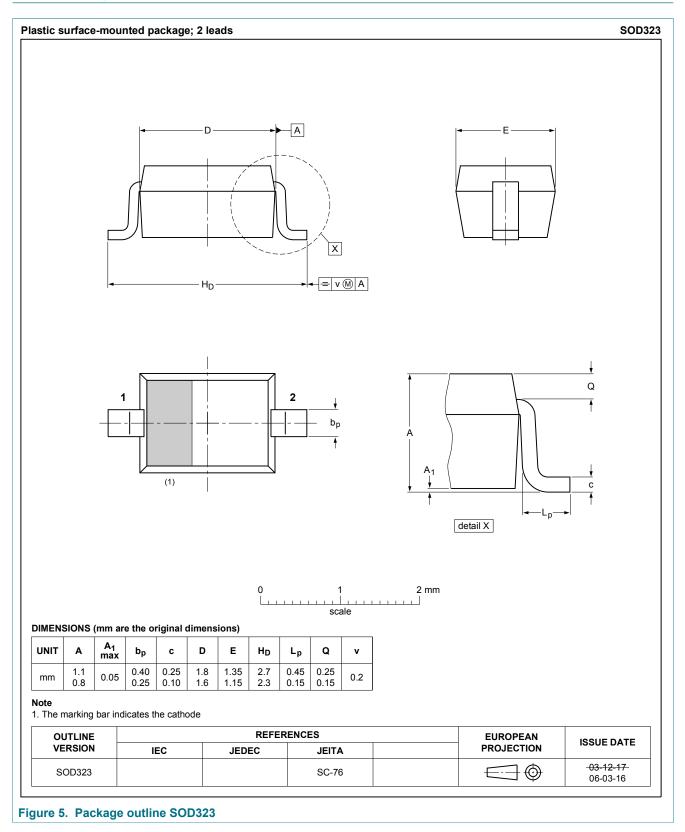




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BAP65-03 Silicon Pin diode

## 9 Package outline



# **10 Revision history**

Table 7. Revision hist							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
BAP65-03 v.5.2	20190128	Product data sheet	-	BAP65-03 v.5.1			
Modifications:	<ul> <li>Changed title</li> </ul>	e to Silicon PIN diode					
BAP65-03 v.5.1	20181211	Product data sheet	-	BAP65-03 v.5			
Modifications:	• • •	<ul> <li>changed Typ value off L<sub>ins</sub> at 2450 MHz to 0.18 dB</li> <li>Changed condition I<sub>F</sub> on L<sub>s</sub>from 10 mA to 100 mA</li> </ul>					
BAP65-03 v.5	20180802	Product data sheet	-	BAP65-03 v.4			
Modifications:	<ul> <li>difications:</li> <li>Section 1.2 "Features and benefits" has been updated.</li> <li>The "Legal information" pages have been updated.</li> </ul>						
BAP65-03 v.4	20040211	Product data sheet	-	BAP65-03 v.3			

## **11 Legal information**

### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

[2] [3] The term 'short data sheet' is explained in section "Definitions".

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Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

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